

RF2048

GENERAL PURPOSE AMPLIFIER

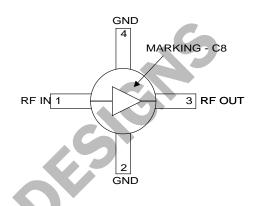
RoHS Compliant & Pb-Free Product Package Style: Micro-X Ceramic

Features

- DC to 8000MHz Operation
- Internally matched Input and Output
- 12dB Small Signal Gain
- +25dBm Output IP3
- +12dBm Output Power
- Single Positive Power Supply

Applications

- Broadband, Low Noise Gain Blocks
- IF or RF Buffer Amplifiers
- Driver Stage for Power Amplifiers
- Final PA for Low Power Applications
- High Reliability Applications
- Broadband Test Equipment



Functional Block Diagram

Product Description

The RF2048 is a general purpose, low cost RF amplifier IC. The device is manufactured on an advanced Gallium Arsenide Heterojunction Bipolar Transistor (HBT) process, and has been designed for use as an easily-cascadable 50Ω gain block. Applications include IF and RF amplification in wireless voice and data communication products operating in frequency bands up to $8000\,\text{MHz}$. The device is self-contained with 50Ω input and output impedances and requires only two external DC biasing elements to operate as specified. With a goal of enhanced reliability, the extremely small Micro-X ceramic package offers significantly lower thermal resistance than similar size plastic packages.

Ordering Information

RF2048 General Purpose Amplifier
RF2048PCBA-41X Fully Assembled Evaluation Board

Optimum Technology Matching® Applied

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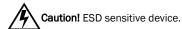
Rev A13 DS070403

RF2048



Absolute Maximum Ratings

Parameter	Rating	Unit
Input RF Power	+13	dBm
Operating Ambient Temperature	-40 to +85	° C
Storage Temperature	-60 to +150	°C



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RoHS status based on EUDirective 2002/95/EC (at time of this document revision).

Davamatav	Specification		Unit	O andiki an		
Parameter	Min.	Тур.	Max.	Unit	Condition	
Overall					T=25 °C, V _D =3.6V, I _{CC} =40 mA	
Frequency Range		DC to 8000		MHz		
Gain		12.3		dB	Freq=100MHz	
		12.3		dB 💧	Freq=1000MHz	
	10	12.4		dB	Freq=2000MHz	
		12.1		dB	Freq=3000MHz	
		11.6			Freq=4000MHz	
		11.5			Freq=6000MHz	
		11.1			Freq=8000MHz	
Gain Flatness		±0.1		dB	100 MHz to 2000 MHz	
Noise Figure		4.5		dB	Freq=2000MHz	
Input VSWR		1.7:1			In a 50Ω system, DC to 3000MHz	
		1.4:1			In a 50Ω system, 3000MHz to 8000MHz	
Output VSWR		1.5:1			In a 50Ω system, DC to 3000MHz	
		1.7:1			In a 50Ω system, 3000MHz to 8000MHz	
Output IP ₃		25.0		dBm	Freq=2000MHz±100kHz, P _{TONE} =-5dBm	
Output P _{1dB}		11.1		dBm	Freq=2000MHz	
Reverse Isolation	7/2	16.5		dB	Freq=2000MHz	
Thermal					I _{CC} =40 mA, P _{DISS} =137 mW (See Note 1.)	
Theta _{JC}		273		°C/W		
Maximum Measured Junction Temperature at DC Bias Conditions		122		°C		
Mean Time To Failure (MTTF)		150,000		years	T _{AMB} =+85 °C	
Power Supply					With 22Ω bias resistor, T=+25°C	
Operating Device Voltage	3.0	3.6	4.0	V	At pin 3 with I _{CC} =40mA	
	3.9	4.5	4.9		At evaluation board connector, I _{CC} =40mA	
Operating Current			40	mA	See Note 2.	
NOTES:	1	1	1	1	I	

NOTES:

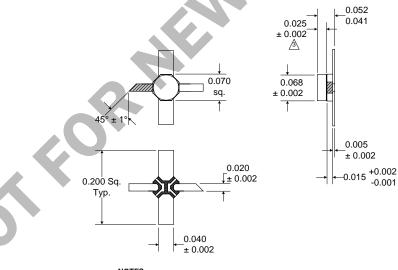
Note 1: The RF2048 must be operated at or below 40 mA in order to achieve the thermal performance stated above. Operating at 40 mA will ensure the best possible combination of reliability and electrical performance.

Note 2: Because of process variations from part to part, the current resulting from a fixed bias voltage will vary. As a result, caution should be used in designing fixed voltage bias circuits to ensure the worst case bias current does not exceed 40 mA over all intended operating conditions.



Pin	Function	Description	Interface Schematic
1	RF IN	RF input pin. This pin is NOT internally DC-blocked. A DC-blocking capacitor, suitable for the frequency of operation, should be used in most applications. DC-coupling of the input is not allowed, because this will override the internal feedback loop and cause temperature instability.	
2	GND	Ground connection. For best performance, keep traces physically short and connect immediately to ground plane.	
3	RF OUT	RF output and bias pin. Biasing is accomplished with an external series resistor and choke inductor to V_{CC} . The resistor is selected to set the DC current into this pin to a desired level. The resistor value is determined by the following equation: $R = \frac{(V_{SUPPLY} - V_{DEVICE})}{I_{CC}}$ Care should also be taken in the resistor selection to ensure that the current into the part never exceeds 40 mA over the planned operating temperature. This means that a resistor between the supply and this pin is always required, even if a supply near 3.6V is available, to provide DC feedback to prevent thermal runaway. Because DC is present on this pin, a DC-blocking capacitor, suitable for the frequency of operation, should be used in most applications. The supply side of the bias network should also be well bypassed.	RF INO
4	GND	Same as pin 2.	

Package Drawing

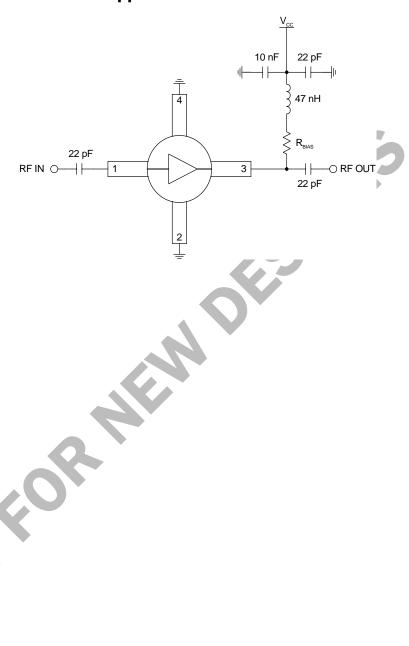


NOTES:

- Shaded lead is pin 1.
 Darkened areas are metallization.
 Dimension applies to ceramic lid minus epoxy coating.

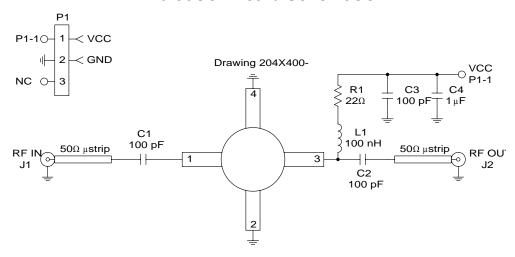


Application Schematic

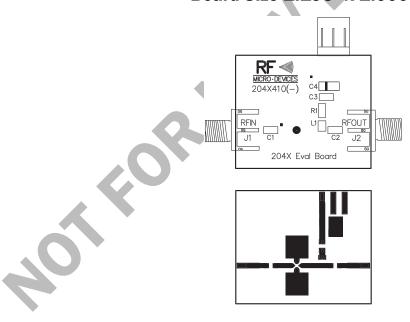




Evaluation Board Schematic

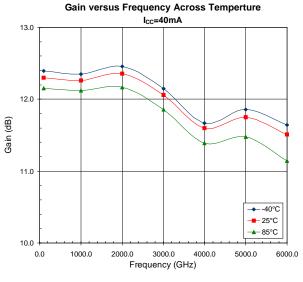


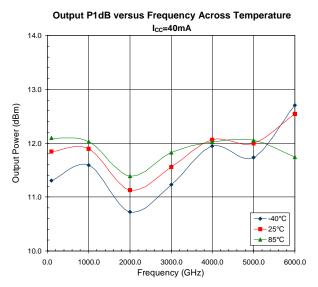
Evaluation Board Layout Board Size 1.195" x 1.000"

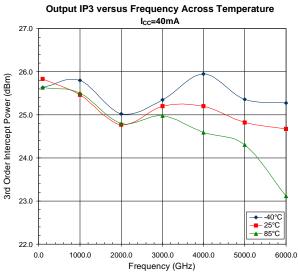


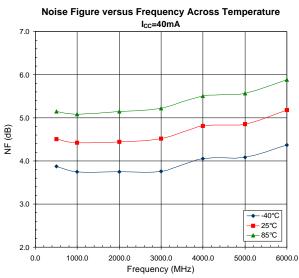
RF2048

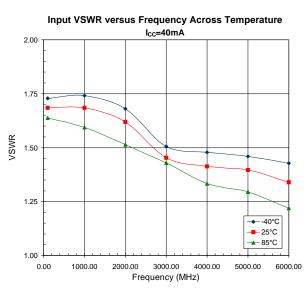


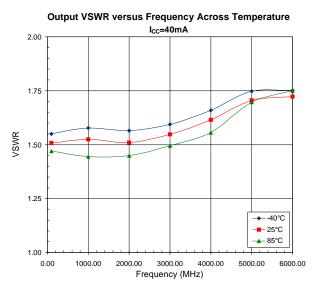




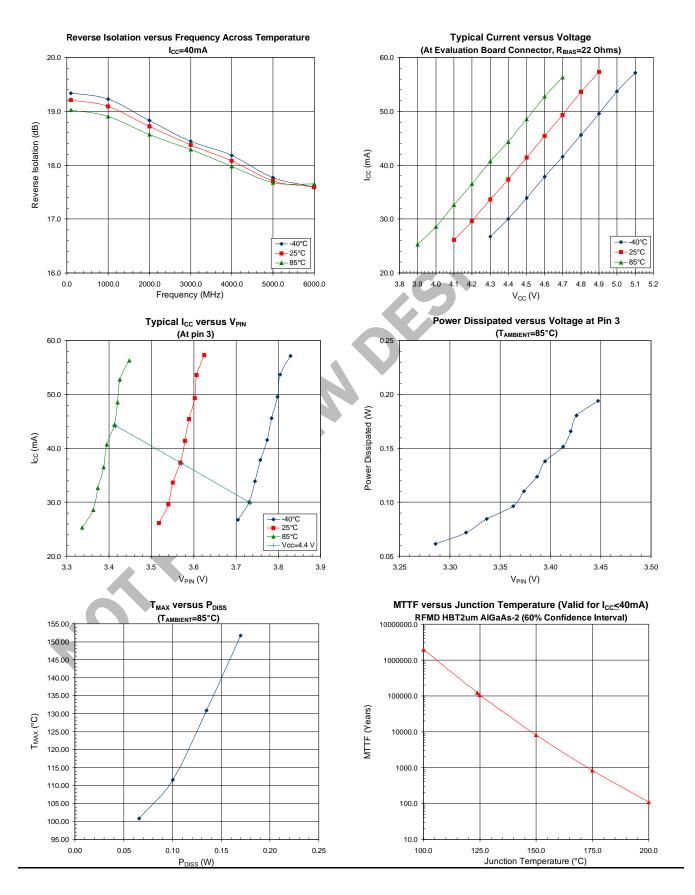














PCB Design Requirements

PCB Surface Finish

The PCB surface finish used for RFMD's qualification process is Electroless Nickel, immersion Gold. Typical thickness is 3μ inch to 8μ inch Gold over 180μ inch Nickel.

PCB Land Pattern Recommendation

PCB land patterns are based on IPC-SM-782 standards when possible. The pad pattern shown has been developed and tested for optimized assembly at RFMD; however, it may require some modifications to address company specific assembly processes. The PCB land pattern has been developed to accommodate lead and package tolerances.

PCB Metal Land Mask Pattern

 $A = 1.90 \times 1.14 \text{ Typ.}$ $B = 0.63 \times 1.90 \text{ Typ.}$

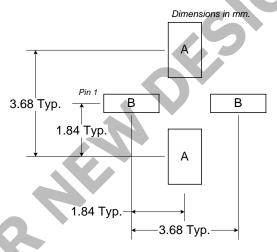


Figure 1. PCB Metal Land Pattern - RF204X (Top View)



PCB Solder Mask Pattern

Liquid Photo-Imageable (LPI) solder mask is recommended. The solder mask footprint will match what is shown for the PCB metal land pattern with a 2mil to 3mil expansion to accommodate solder mask registration clearance around all pads. The center-grounding pad shall also have a solder mask clearance. Expansion of the pads to create solder mask clearance can be provided in the master data or requested from the PCB fabrication supplier.

$$A = 2.06 \times 1.30 \text{ Typ.}$$

 $B = 0.79 \times 2.06 \text{ Typ.}$

Dimensions in mm.

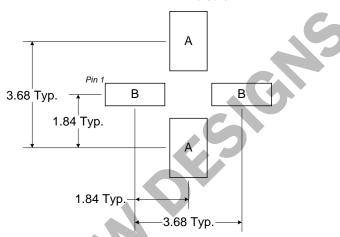


Figure 2. PCB Solder Mask - RF204X (Top View)



